

## Silicon Standard Recovery Diode

**V<sub>RRM</sub> = 50 V - 600 V**  
**I<sub>F</sub> = 60 A**

### Features

- High Surge Capability
- Types up to 600 V V<sub>RRM</sub>

**DO-5 Package**



### Maximum ratings, at T<sub>j</sub> = 25 °C, unless otherwise specified

| Parameter  | Symbol            | Conditions                                      | 1N2128A (R) | 1N2129A (R) | 1N2130A (R) | 1N2131A (R) | Unit |
|--|-------------------|---|-------------|-------------|-------------|-------------|------|
| Repetitive peak reverse voltage                      | V <sub>RRM</sub>  |   | 50          | 100         | 150         | 200         | V    |
| RMS reverse voltage                                  | V <sub>RMS</sub>  |   | 35          | 70          | 106         | 140         | V    |
| DC blocking voltage                                  | V <sub>DC</sub>   |   | 50          | 100         | 150         | 200         | V    |
| Continuous forward current                           | I <sub>F</sub>    | T <sub>C</sub> ≤ 150 °C                         | 60          | 60          | 60          | 60          | A    |
| Surge non-repetitive forward current, Half Sine Wave | I <sub>F,SM</sub> | T <sub>C</sub> = 25 °C, t <sub>p</sub> = 8.3 ms | 1050        | 1050        | 1050        | 1050        | A    |
| Operating temperature                                | T <sub>j</sub>    |   | -65 to 200  | -65 to 200  | -65 to 200  | -65 to 200  | °C   |
| Storage temperature                                  | T <sub>stg</sub>  |   | -65 to 200  | -65 to 200  | -65 to 200  | -65 to 200  | °C   |

### Electrical characteristics, at T<sub>j</sub> = 25 °C, unless otherwise specified

| Parameter                           | Symbol            | Conditions                                    | 1N2128A (R) | 1N2129A (R) | 1N2130A (R) | 1N2131A (R) | Unit |
|-------------------------------------|-------------------|---|-------------|-------------|-------------|-------------|------|
| Diode forward voltage               | V <sub>F</sub>    | I <sub>F</sub> = 60 A, T <sub>j</sub> = 25 °C | 1.1         | 1.1         | 1.1         | 1.1         | V    |
| Reverse current                     | I <sub>R</sub>    | V <sub>R</sub> = 50 V, T <sub>j</sub> = 25 °C | 10          | 10          | 10          | 10          | µA   |
| <b>Thermal characteristics</b>      |                   |   |             |             |             |             |      |
| Thermal resistance, junction - case | R <sub>thJC</sub> |   | 0.65        | 0.65        | 0.65        | 0.65        | °C/W |

